100mA Regulated Charge Pump

■ General Description

The AME7730 is a charge pump voltage doublers that delivers a regulated output. No external inductor is required for operation. Using three small capacitors, the AME7730 can deliver up to 100mA to the voltage regulated output. The AME7730 features very low output ripple and high efficiency over a large portion of its load range making this device ideal for battery-powered applications. Furthermore, the combination of few external components and small package size keeps the total converter board area to a minimum in space restricted applications.

The AME7730 contains a thermal management circuit to protect the device under continuous output short circuit conditions.

The AME7730 is available in SOT-26 / TSOT-26 package and is rated from -40°C to 85°C.

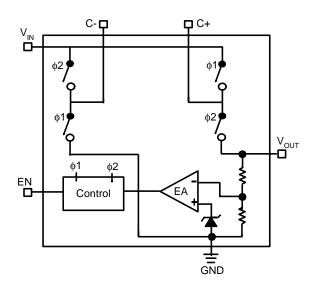
■ Features

- Input Voltage Range: 2.7V to 5V
- Accurate to with ±4%
- Output Current: 100mA with $V_{IN} >= 3.0V$

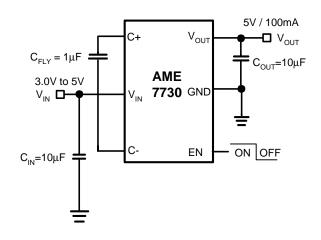
50mA with $V_{IN} >= 2.7V$

- 1MHz Switching Frequency
- Shutdown Mode < 1μA
- Short Circuit Protection
- Over Temperature Protection
- All AME's Lead Free Product Meet RoHS Standards

■ Functional Block Diagram



■ Typical Application



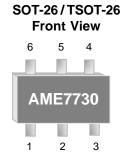
■ Applications

- Cellular Phones
- Digital Cameras
- PDAs LCD displays
- LED / Display Back Light Driver
- LEDs for Comera Flash





■ Pin Configuration



AME7730AEEY

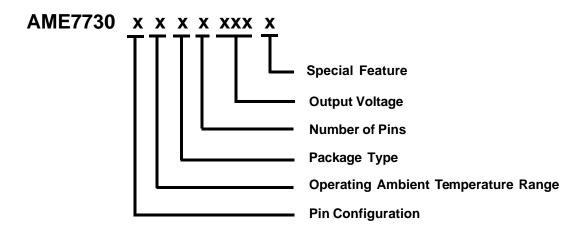
- 1. OUT
- 2. GND
- 3. EN
- 4. C-
- 5. IN
- 6. C+
- * Die Attach: Conductive Epoxy

■ Pin Description

Pin Number	Pin Name	Description
1	OUT	Regulator Output Pin. V_{OUT} should be bypassed with a $10 \mu F$ low ESR ceramic capacitor
2	GND	Ground Pin Connection
3	EN	Enable Input. Active Low disable the regulator
4	C-	Pump Capacitor Negative Terminal
5	IN	Input Supply Pin. $V_{IN} \text{ should be bypassed with a } 10 \mu\text{F low ESR ceramic capacitor}$
6	C+	Pump Capacitor Positive Terminal



■ Ordering Information



Pin Configuration	Operating Ambient Temperature Range	Package Type	Number of Pins	Output Voltage	Special Feature
A 1. OUT (SOT-26) 2. GND (TSOT-26) 3. EN 4. C- 5. IN 6. C+	E: -40°C to 85°C	E: SOT-2X	Y: 6	500: V = 5V	Z: Lead free Y: Lead free & Low profile

■ Ordering Information

Part Number	Marking*	Output Voltage	Package	Operating Ambient Temperature Range
AME7730AEEY500Y	BCAww	5V	TSOT-26	- 40°C to 85°C
AME7730AEEY500Z	BCAww	5V	SOT-26	- 40°C to 85°C

Note: www represents date code and pls refer Date Code Rule on Package Dimension.

Please consult AME sales office or authorized Rep./Distributor for the availability of output voltage and package type.

^{*} A line on top of the first letter represents lead free plating such as BCA



■ Absolute Maximum Ratings

Parameter	Maximum	Unit
Input Voltage, Output Voltage, C-, C+	-0.3 to 5.5	V
EN	-0.3 to V _{IN} + 0.3	V
ESD Classification	B*	

Note: Caution: Stress above the listed in absolute maximum ratings may cause permanent damage to the device.

■ Recommended Operating Conditions

Parameter	Symbol	Rating	Unit
Ambient Temperature Range	T _A	- 40 to 85	°C
Junction Temperature Range	TJ	- 40 to 125	°C
Storage Temperature Range	T _{STG}	- 65 to 150	°C

■ Thermal Information

Parameter	Package	Die Attach	Symbol	Maximum	Unit
Thermal Resistance* (Junction to Case)			θιс	81	°C/W
Thermal Resistance (Junction to Ambient)	SOT-26 TSOT-26	I Conductive Enoxy	$\theta_{\sf JA}$	260	*C/VV
Internal Power Dissipation			P_{D}	400	mW
Solder Iron (10 Sec)**	350	°C			

^{*} Measure θ_{JC} on center of molding compound if IC has no tab.

^{*} HBM B: 2000V ~ 3999V

^{**} MIL-STD-202G 210F

100mA Regulated Charge Pump

■ Electrical Characteristics

 $V_{_{IN}} = V_{_{EN}} = 3V, \ C_{_{pump}} = 1\mu F, \ C_{_{IN}} = 10\mu F, \ C_{_{OUT}} = 10\mu F, \ Typical \ values \ are \ at \ T_{_A} = 25^{\circ}C, \ unless \ otherwise \ noted.$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Input Voltage	V _{IN}	V _{OUT} = 5.0V	2.7		5	V
Output Voltage	V _{OUT}	I _{OUT} <= 50mA, 2.7V < V _{IN} < 5V	4.8	5	5.2	V
Output voltage	VOUT	I _{OUT} <= 100mA, 3.0V < V _{IN} < 5V	4.8	5	5.2	V
Quiescent Current	l _Q	$2.7V < V_{IN} < 5V, I_{OUT} = 0mA, V_{EN} = V_{IN}$		60	100	μА
Shutdown Current	l	$2.7V < V_{IN} < 3.6V, I_{OUT} = 0mA, V_{EN} = 0$		0.01	1	μA
Shataown Current	I _{SHDN}	$3.6V < V_{IN} < 5V$, $I_{OUT} = 0$ mA, $V_{EN} = 0$			2.5	μΛ
Short Circuit Current Limit	I _{SC}	$V_{IN} = V_{EN} = 3V$, $V_{OUT} = GND$		300		mA
Ripple Voltage ¹	V _{RIPPLE}	$V_{IN} = 2.7V, I_{OUT} = 50mA, V_{OUT} = 5V$		25		mVp-p
Ripple Voltage		V _{IN} = 3V, I _{OUT} = 100mA, V _{OUT} = 5V 30			шурр	
Efficiency	η	$V_{IN} = 2.7V, I_{OUT} = 50mA, V_{OUT} = 5V$		90		%
Frequency	fosc	Oscillator Free Running		1.0		MHz
EN Input Threshold High	V _{EH}		1.3			V
EN Input Threshold Low	V _{EL}				0.6	V
EN Input Current	I _{EN}	$V_{EN} = V_{IN}, V_{EN} = GND$			0.1	μА
Over Temperature Shutdown	OTS			160		°C
Over Temperature Hysterisis	ОТН			20		°C

Note 1: Effective series resistance (ESR) of capacitors is $< 0.1\Omega$.

100mA Regulated Charg Pump

■ Detailed Description

The AME7730 uses charge pump voltage doubler structure to boost an input voltage to a regulated output voltage. Regulation is achieved by decting the charge pump output voltage through an internal resistor divider network. A charge pump circuit is enabled when the divided output voltage below a preset trip point controlled by an internal comparator.

Short Circuit and Thermal Protection

The AME7730 has a thermal protection and shutdown circuit that continuously monitors the IC junction temperature. If the thermal protection circuit senses the die temperature exceeding approximately 160°C, the thermal shutdown will disable the charge pump switching cycle operation, the thermal limit system has 20°C of system hysteresis before the charge pump can reset. Once the over current event is removed from the output and the junction temperature drops below 140°C, the charge pump will the become active again. The thermal protection system will cycle on and off if an output short circuit condition persists. This will allow the AME7730 to operate indefinitely a short circuit condition with out damage to the device.

■ Shutdown Mode

A control pin EN on the regulator can be used to place the device into an energy-saving shutdown mode. In this mode, the output is disconnected from the input as long as $V_{\rm IN}$ is greater than or equal to minimum $V_{\rm IN}$ and input quiescent current is reduced to $1\mu A$ maximum.

■ Capacitor Selection

For minimum output voltage ripple, the output capacitor C_{OUT} should be a ceramic, surface-mount type. Tantalum capacitors generally have a higher Effective Series Resistance (ESR) and may contribute to higher output voltage ripple. Leaded capacitors also increase ripple due to the higher inductance of the package itself. To achieve best operation with low input voltage and high load current, the input and pump capacitors (C_{IN} , C_{PUMP} respectively) should also be surface-mount ceramic types. In all cases, X7R or X5R dielectric are recommended.

With ligh loads or higher input voltage, a smaller $0.1\mu F$ pump capacitor (C_{PUMP}) and smaller $1\mu F$ input and output capacitor (C_{IN} and C_{OUT} respectively) can be used. To minimize output voltage ripple, increase the output capacitor C_{OUT} to $10\mu F$ or larger.

■ Efficiency

The efficiency of the charge pump regulator depends on the applied input voltage, the load current, and the internal operation mode of the device.

The approximate efficiency is given by:

Efficiency (%) =
$$V_{OUT} / 2V_{IN}$$
 . 100 %

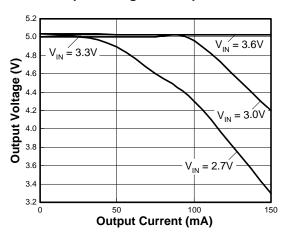
■ Layout

Large ripple currents flow in the $V_{\rm IN}$ and $V_{\rm OUT}$ traces. To minimize both input and output ripple, keep the capacitors as close as possible to the regulator using short, direct circuit traces.

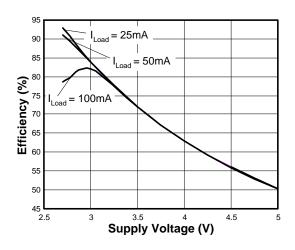
The trace lengths from the input and output capacitors have been kept as short as possible. A star ground system has been implemented, with GND pin as the center of the star. No ground plane is provided in other layers as this will provide capacitive coupling for noise spikes.



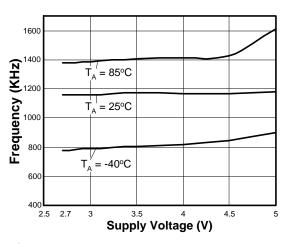
Output Voltage vs. Output Current



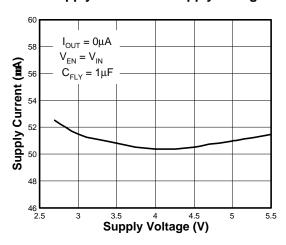
Efficiency vs. Supply Voltage



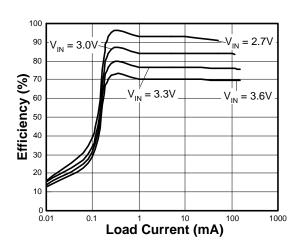
Oscillator Frequency vs. Supply Voltage



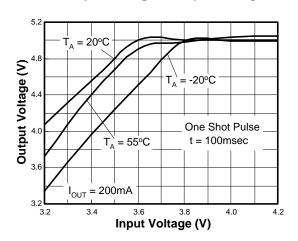
Supply Current vs. Supply Voltage



Efficiency vs. Load Current

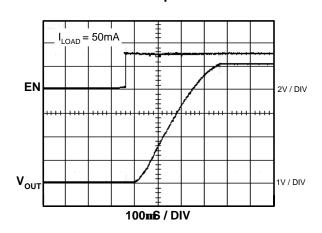


Output Voltage vs. Input Voltage

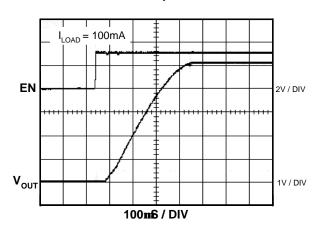


100mA Regulated Charg Pump

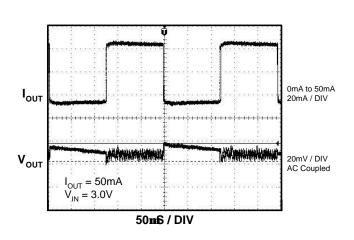
Startup Time



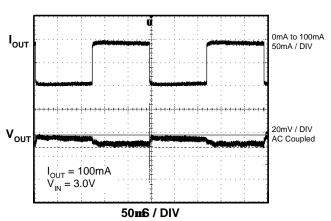
Startup Time



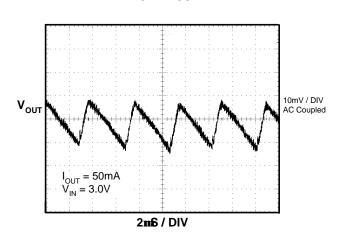
Load Transient Response



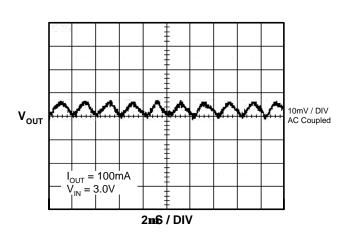
Load Transient Response



Output Ripple



Output Ripple





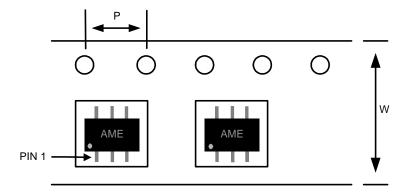


■ Date Code Rule

	Marking		Date	Code	Year
Α	Α	Α	W	W	xxx0
Α	Α	Α	W	W	xxx1
Α	Α	Α	W	W	xxx2
Α	Α	Α	W	W	xxx3
Α	Α	<u>A</u>	W	W	xxx4
Α	Α	<u>A</u>	W	W	xxx5
Α	Α	<u>A</u>	W	W	xxx6
Α	Α	<u>A</u>	W	W	xxx7
Α	<u>A</u>	Α	W	W	8xxx
Α	<u>A</u>	Α	W	W	xxx9

■ Tape and Reel Dimension

SOT-26



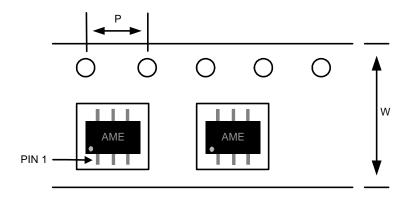
Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Part Per Full Reel	Reel Size
SOT-26	8.0±0.1 mm	4.0±0.1 mm	3000pcs	180±1 mm



■ Tape and Reel Dimension

TSOT-26



Carrier Tape, Number of Components Per Reel and Reel Size

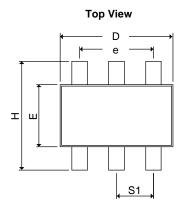
Package	Carrier Width (W)	Pitch (P)	Part Per Full Reel	Reel Size
TSOT-26	8.0±0.1 mm	4.0±0.1 mm	3000pcs	180±1 mm





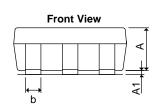
■ Package Dimension

SOT-26



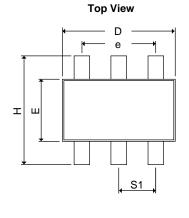


Side View



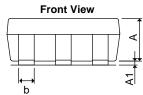
SYMBOLS	MILLIN	IETERS	INCHES		
STWIDOLS	MIN	MAX	MIN	MAX	
Α	1.20	REF	0.047	2REF	
A ₁	0.00	0.15	0.0000	0.0059	
b	0.30	0.55	0.0118	0.0217	
D	2.70	3.10	0.1063	0.1220	
E	1.40	1.80	0.0551	0.0709	
е	1.90	BSC	0.074	8 BSC	
Н	2.60	3.00	0.10236	0.11811	
L	0.37	REF	0.0146REF		
q 1	0°	10°	0° 10°		
S ₁	0.95	REF	0.037	4REF	

TSOT-26





Side View



SYMBOLS	MILLIN	IETERS	INCHES		
STWIDOLS	MIN	MAX	MIN	MAX	
A+A ₁	0.90	1.25	0.0354	0.0492	
b	0.30	0.50	0.0118	0.0197	
D	2.70	3.10	0.1063	0.1220	
E	1.40	1.80	0.0551	0.0709	
е	1.90	BSC	0.0748	0 BSC	
Н	2.40	3.00	0.09449	0.11811	
L	0.35BSC		0.0138BSC		
q1	0°	10°	0° 10°		
S ₁	0.95	BSC	0.037	4BSC	



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